

PRELIMINARY

Wideband Linear Amplifier

THM2004J

**SiGe HBT MMIC
Wideband Linear Amplifier**

Descriptions

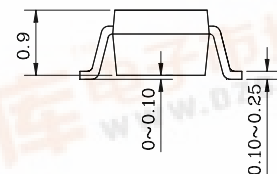
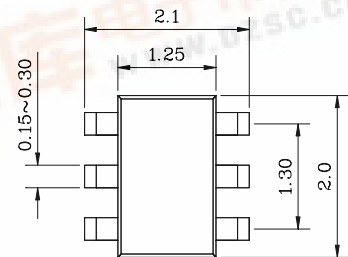
THM2004J is a high performance cascadeable 50-ohm amplifier. This RFIC uses the latest Silicon Germanium Hetero Junction Bipolar Transistor (TAHB09) process of Tachyonics Co., which has 30GHz f_T (Normal). THM2004J uses a multi feedback cascade amplifier topology with resistive feedback for broad band performance as well as stability over its entire temperature range. THM2004J also has internally matched 50 ohm impedance and wide bandwidth.

Features

- Wide band operation : $f_{3dB} = 2.2\text{GHz}$
- Single Voltage Supply
- Internally Matched to 50 Ohm Input & Output
- High Power Gain : 25dB at 1000MHz
- Saturated Output Power : $P_{o(sat)} = +12\text{dBm}$ at 1000MHz

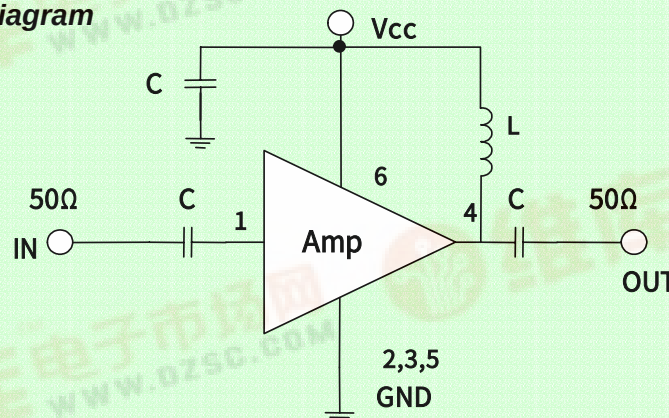
Applications

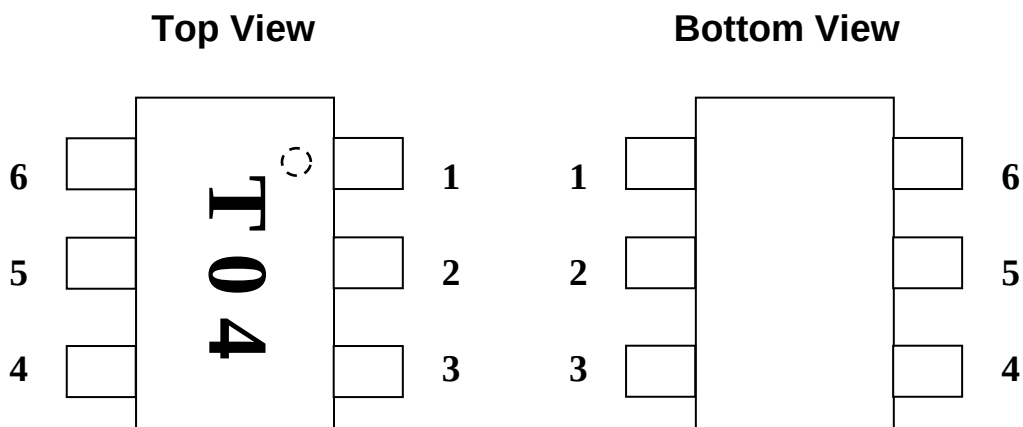
- DBS, LNB , Medium Output
- Transmission Stage Buffer (Mobile Communication)
- IF/RF Buffer Amplifier



SOT363

Function Block Diagram



Pin Configuration**Pin Description**

Pin No.	Name	Description
1	IN	RF SIGNAL INPUT
2	GND	GROUND
3	GND	GROUND
4	OUT	RF SIGNAL OUTPUT
5	GND	GROUND
6	VCC	POWER SUPPLY

Absolute Maximum Ratings

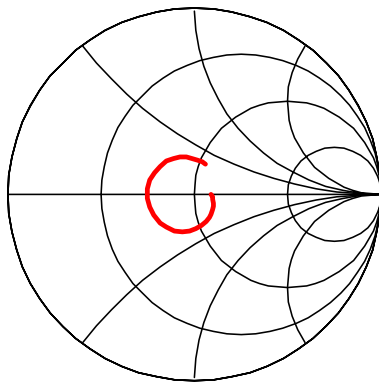
Parameter	Rating	Unit
Supply Voltage	6	V
Supply Current	60	mA
RF Input Power	+10	dBm
Operation Temperature Range	-40 to +85	°C
Maximum Junction Temperature	+150	°C
Storage Temperature Range	-55 to +150	°C

Electrical Characteristics(T_A = 25°C, V_{CC} = 5V, L1 = 220nH, Z_S = Z_L = 50Ω)

Symbol	Parameter	Condition	Specification			Unit
			Min.	Typ.	Max.	
f _{3dB}	Upper 3dB cut off frequency		2000	2200	-	MHz
G _p	Power Gain	f = 1000MHz	22	25	27	dB
P _{O(sat)}	Saturated output power	f = 1000MHz	+9	+12	-	dBm
RL _{IN}	Input Return Loss	f = 1000MHz	9	16	-	dB
RL _{OUT}	Output Return Loss	f = 1000MHz	7	13	-	dB
NF	Noise Figure	f = 1000MHz	-	4.0	6.0	dB
ISL	Isolation	f = 1000MHz	26	32	-	dB
I _{CC}	Bias Current	No Input Signal	19	25	32	mA

Typical Characteristics

Input Reflection Coefficient



Output Reflection Coefficient

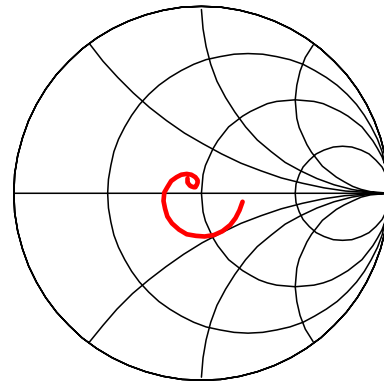


Fig1. Input/Output Impedance

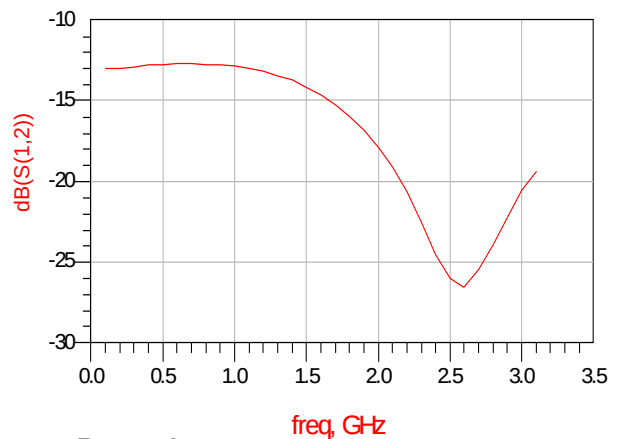
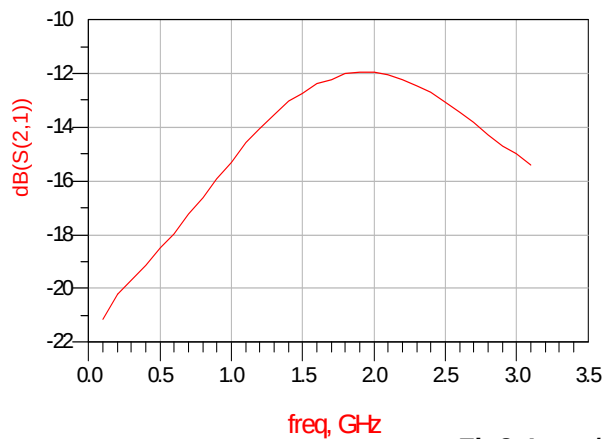


Fig2. Input/Output Return Loss

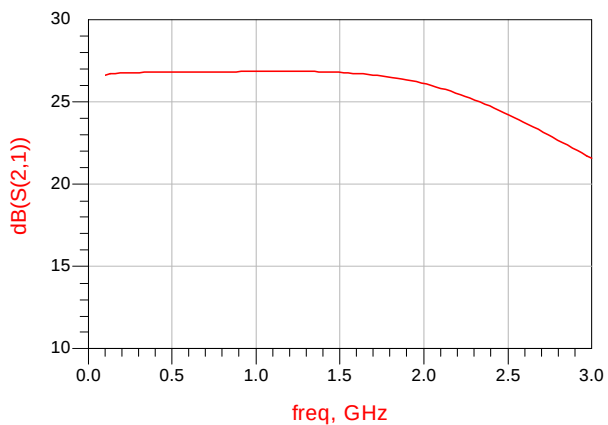


Fig3. Small Signal Gain

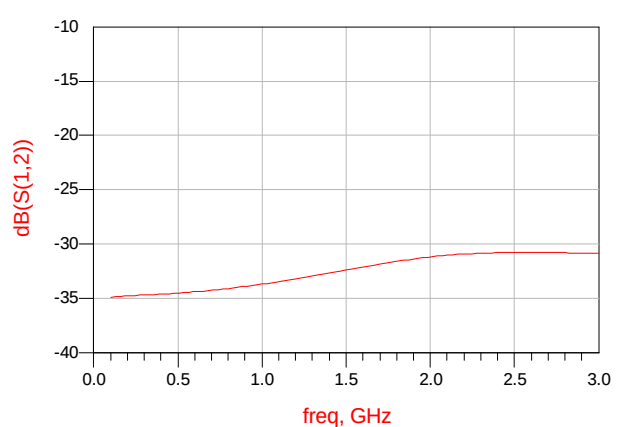
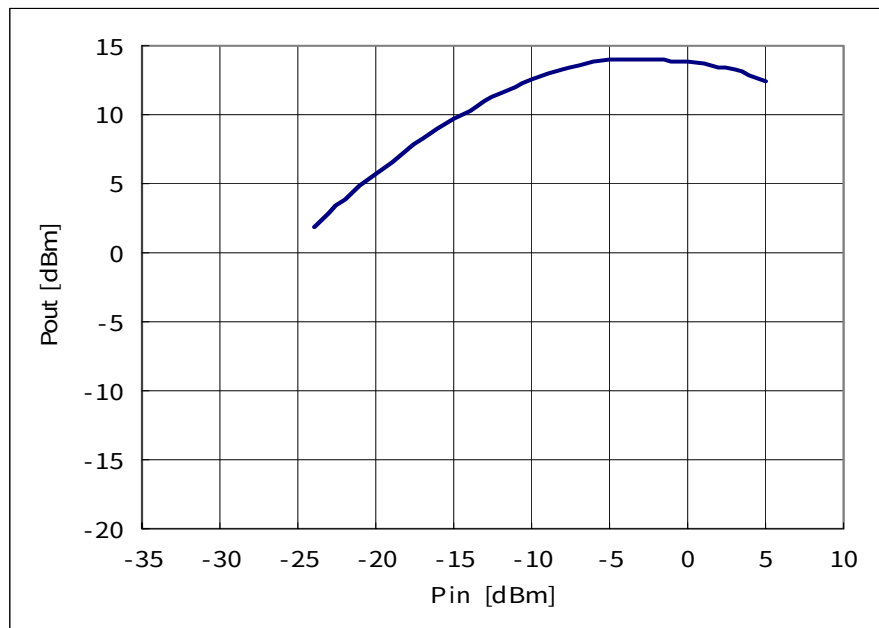
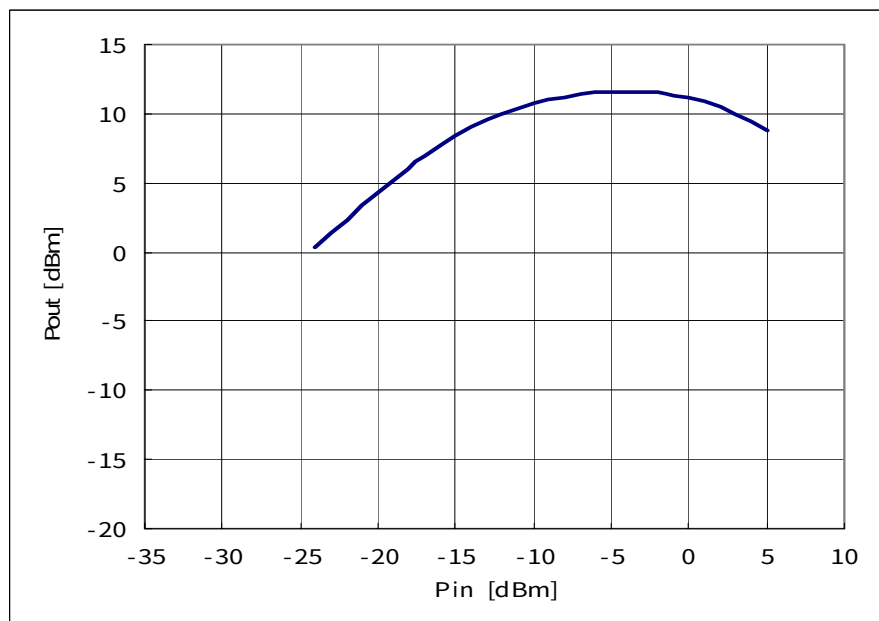
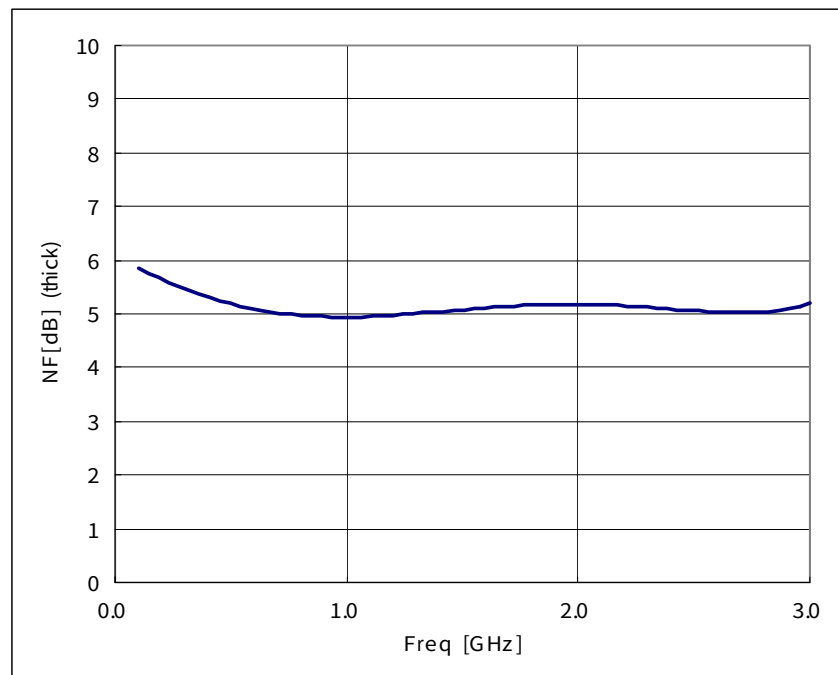
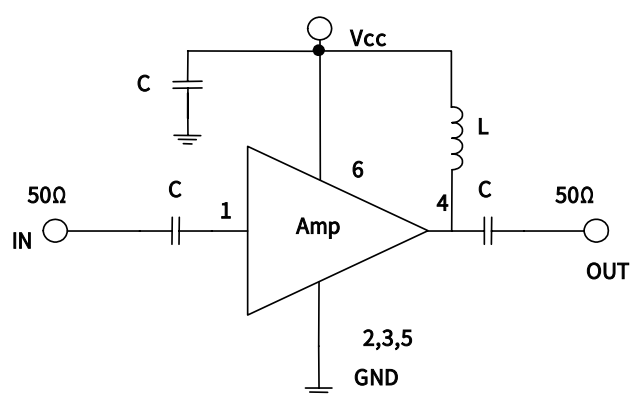


Fig4. Isolation

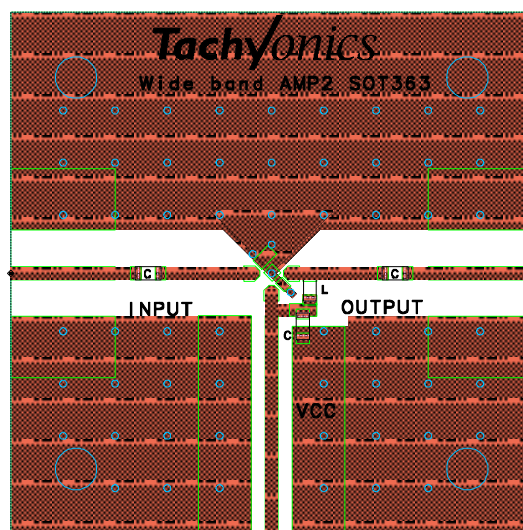
Typical Characteristics**Fig5. 1000MHz Power Sweep****Fig6. 2000MHz Power Sweep**

Typical Characteristics**Fig7. Noise Figure**

Test Circuit



Evaluation Board

Board Size 30 x 30 mm²

NOTE
 Board Thickness 0.3mm
 Board Material FR4
 Double Layer

Component List

Name	Value	Remark
C	1000 pF	100MHz or higher frequency
L	220 nH	100MHz or higher frequency